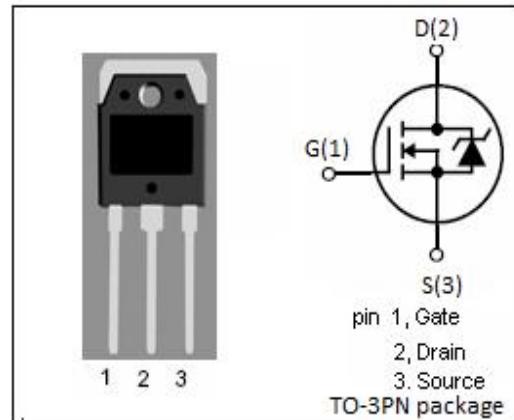


# isc N-Channel MOSFET Transistor

# 2SK3271

## • FEATURES

- With TO-3P packaging
- High speed switching
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



## • APPLICATIONS

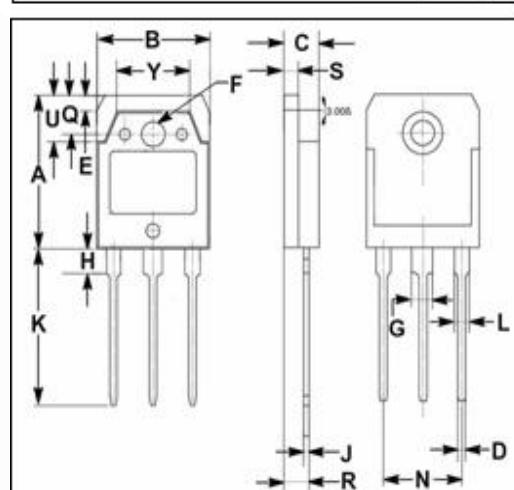
- Power supply
- Switching applications

## • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GSS}$	Gate-Source Voltage	$\pm 30$	V
$I_D$	Drain Current-Continuous	100	A
$I_{DM}$	Drain Current-Single Pulsed	400	A
$P_D$	Total Dissipation	155	W
$T_j$	Operating Junction Temperature	-55~150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.81	$^\circ\text{C}/\text{W}$



DIM	mm	
	MIN	MAX
A	19.60	20.30
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	19.80	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.20
Y	9.90	10.10

**isc N-Channel MOSFET Transistor****2SK3271****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D=1\text{mA}$	60			V
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_D=10\text{mA}$	2.5		3.5	V
$\text{R}_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D=40\text{A}$		5.0	6.5	$\text{m}\Omega$
$\text{I}_{\text{GSS}}$	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 30\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			$\pm 0.1$	$\mu\text{A}$
$\text{I}_{\text{DSS}}$	Drain-Source Leakage Current	$\text{V}_{\text{DS}}=60\text{V}; \text{V}_{\text{GS}}= 0;$		1	100	$\mu\text{A}$
$\text{V}_{\text{SDF}}$	Diode forward voltage	$\text{I}_{\text{SD}}=80\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.5	V